

Growth and Anion Exchange Conversion of CH₃NH₃PbX₃ Nanorod Arrays for Light-Emitting Diodes

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ABSTRACT: The nanowire and nanorod morphology offers great advantages for application in a range of optoelectronic devices, but these high quality nanorod arrays are typically based on high temperature growth techniques. Here, we demonstrate the successful room temperature growth

of a hybrid perovskite ($\text{CH}_3\text{NH}_3\text{PbBr}_3$) nanorod array, and we also introduce a new low temperature anion exchange technique to convert the $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array into a $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorod array while preserving morphology. We demonstrate the application of both these hybrid perovskite nanorod arrays for LEDs. This work highlights the potential utility of post-synthetic interconversion of hybrid perovskites for nano-structured optoelectronic devices such as LEDs, which enables new strategies for the application of hybrid perovskites.

KEYWORDS: Hybrid perovskite nanorod array, perovskite light-emitting diode, $\text{CH}_3\text{NH}_3\text{PbBr}_3$, $\text{CH}_3\text{NH}_3\text{PbI}_3$, nanorod array light-emitting diode, anion exchange

Recently, hybrid perovskites such as $\text{CH}_3\text{NH}_3\text{PbI}_3$ and $\text{CH}_3\text{NH}_3\text{PbBr}_3$ have disrupted work on other photovoltaic technologies with efficiencies approaching 20%.¹⁻⁴ This class of materials offers remarkable photoluminescence quantum efficiencies (PLQE) up to 70% and minority carrier diffusion lengths up to 175 μm , and these materials are can be easily synthesized via low temperature solution processing and with extraordinary band gap tunability.^{5,6} In light of this, there have been other proposed uses for these perovskite materials for optoelectronic devices beyond solar cells such as for lasers, photodetectors, and LEDs.⁷⁻¹² Previously, thin film LEDs (~ 15 nm) of $\text{CH}_3\text{NH}_3\text{PbBr}_3$ demonstrated external quantum efficiencies of 0.4% at 530 nm.¹⁰ Although the demonstration of electroluminescence was impressive, it was believed that the efficiency was limited by discontinuities in the thin perovskite film that provide shunt paths.¹⁰ Recently, Li et al. demonstrated electroluminescence with peak external quantum efficiencies reaching 1.2% from hybrid perovskite nanocrystals blended with a thin polyimide dielectric

polymer.¹² These results demonstrate the promise of hybrid perovskites for the development of high efficiency solution-processed LEDs.

Nanorod arrays have also been proposed as promising morphologies for LEDs because the vertically oriented nanorod array geometry offers advantages in terms of inherently large active surface area, higher charge carrier injection efficiencies, and improved strain relaxation from thermal expansion caused by heating.¹³⁻¹⁶ Surface roughness achieved by etching has been shown to improve the light extraction of conventional light-emitting diodes.¹⁷ The naturally large surface area of nanorod arrays combined with the potential difficulty of etching hybrid perovskites without inducing damage makes the perovskite nanorod array an ideal platform for hybrid perovskite LEDs. The nanorod array may also act as a waveguide to improve the extraction of light from the active layer.^{16,18,19} Overall, nanorod arrays offer a potential means to realize higher external quantum efficiencies for LEDs.

At present, there are limited examples of any device made from hybrid perovskite nanorods or nanowires, although recent work demonstrates their application for solar cells and single nanowire lasers.^{20,21} The hybrid perovskites possess a cubic or tetragonal crystal symmetry, which does not favor the crystallization of one-dimensional nanorods. Recently, there have been several examples of hybrid perovskite nanowire synthesis using various approaches.²⁰⁻²⁴ In particular, perovskites grown using lead acetate as a precursor have been shown to yield high quality perovskite crystals, even in aqueous solution.^{21, 25-29} These high quality hybrid perovskite crystals grown from a lead acetate precursor exhibit a reduced defect density, which makes this precursor an attractive choice for nanorod array synthesis.^{21,28,29}

The potential for post-synthetic interconversion and alloying is another fascinating property of the hybrid perovskites. The ability to exchange ions has proven to be a highly useful method for the synthesis of new, functional nanostructures.³⁰⁻³² The ability to interconvert the halide anion could potentially be another means for controlling the properties towards new functional devices based on hybrid perovskites. However, anion exchanges usually suffer from sluggish reaction kinetics and poor morphology retention, which are attributed to the low mobility and large ionic radius of the anion, so the reaction typically results in hollow particles.^{30,33} Recently, Pellet et al. has reported the anion exchange of hybrid perovskite films in the solution phase.³⁴ This is in agreement with the observation that the photoluminescence of $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Br}_x$ shows photoinduced reversible phase segregation, which likely constitutes a reversible *in situ* anion exchange.³⁵ In addition, it has recently been shown that Br_2 and I_2 gas can be used to convert $\text{CH}_3\text{NH}_3\text{PbI}_3$ to $\text{CH}_3\text{NH}_3\text{PbBr}_3$ or $\text{CH}_3\text{NH}_3\text{PbCl}_3$ through redox chemistry.³⁶ However, to our knowledge, the complete conversion of $\text{CH}_3\text{NH}_3\text{PbBr}_3$ to $\text{CH}_3\text{NH}_3\text{PbI}_3$ has not been previously demonstrated by any method. The ion exchange chemistry of these hybrid perovskites presents a new chemical degree of freedom to explore in the synthesis and application of these materials.

In this work, we demonstrate a solution-phase growth of high quality $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod arrays, which we convert to $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorod arrays using a simple morphology-preserving anion exchange reaction. Both of these hybrid perovskite nanorod arrays were used to fabricate the first hybrid perovskite nanorod array LEDs as a demonstration of their utility for optoelectronic devices. The structure of the LED device is ITO/PEDOT:PSS/ $\text{CH}_3\text{NH}_3\text{PbX}_3$ /F8/Ca/Ag, where 9,9-dioctylfluorene (F8) and poly(3,4-ethylenedioxythiophene) polystyrene sulfonate (PEDOT:PSS) are used to facilitate the injection of electrons and holes into the perovskite active layer, respectively.^{10,11} In this work, the

$\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array exhibits green electroluminescence at 533 nm with a small FWHM of 26 nm. To synthesize $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorod arrays, the conversion of $\text{CH}_3\text{NH}_3\text{PbBr}_3$ to $\text{CH}_3\text{NH}_3\text{PbI}_3$ by anion exchange was achieved by annealing at 140 to 150 °C in $\text{CH}_3\text{NH}_3\text{I}$ vapor to convert the $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array into a $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorod array with retention of the initial morphology. This $\text{CH}_3\text{NH}_3\text{PbI}_3$ also exhibits electroluminescence as an LED at 782 nm, which demonstrates the quality of the $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorod array produced by anion exchange.

The direct growth of the vertical $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array is accomplished by coating a saturated methanolic solution of lead acetate onto a PEDOT:PSS coated ITO/glass substrate. This substrate was then placed in a solution of $\text{CH}_3\text{NH}_3\text{Br}$ in 2-propanol to form orange $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod arrays. As shown by scanning electron microscopy (SEM) and transmission electron microscopy (TEM), the individual $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorods exhibit a square cross-section with lengths exceeding 1 μm and diameters exceeding 100 nm (Figure 1a,b). Although these nanorods are rapidly damaged by the electron beam in the TEM, the selected area electron diffraction (SAED) pattern shown in the inset of Figure 1b was indexed to the [001] zone axis of cubic $\text{CH}_3\text{NH}_3\text{PbBr}_3$. This SAED pattern reflects that these $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorods are single crystalline. The square cross-section of the nanorod reflects the cubic symmetry of the $\text{CH}_3\text{NH}_3\text{PbBr}_3$ unit cell. As shown in the inset cross-sectional SEM image of the $\text{CH}_3\text{NH}_3\text{PbBr}_3$ array, a buffer layer of $\text{CH}_3\text{NH}_3\text{PbBr}_3$ particles with a thickness of over 100 nm also covers the substrate (Figure 1a). The X-ray diffraction (XRD) pattern of the $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array can be indexed to cubic phase $\text{CH}_3\text{NH}_3\text{PbBr}_3$ with high phase purity as shown in Figure 1c.

The optical properties of the $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array highlight their potential for optoelectronic devices. The optical absorption spectrum of the $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array is shown in Figure 2a. The absorption onset is around 530 nm, which is consistent with the fact that $\text{CH}_3\text{NH}_3\text{PbBr}_3$ is known to have a band gap at 2.3 eV.³⁷ As shown in Figure 2b, the room temperature photoluminescence of the $\text{CH}_3\text{NH}_3\text{PbBr}_3$ peaks at 534 nm with a relatively narrow FWHM of 26 nm under 325 nm excitation by a HeCd laser. No broad sub-bandgap emission typically associated with defects is observed. The low temperature photoluminescence of the $\text{CH}_3\text{NH}_3\text{PbBr}_3$ at 6 K also exhibits a significant red shift in the photoluminescence to a peak emission at 541 nm with a FWHM of 14 nm, which is a trend opposite of the Varshni relation. In this case, the $\text{CH}_3\text{NH}_3\text{PbBr}_3$ undergoes multiple phase transitions at 236.3 K (to a tetragonal phase), 154.0 K (to another tetragonal phase), and 148.8 K (to an orthorhombic phase), which may account for the observed red shift.³⁸ The time-resolved photoluminescence shows that the $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod arrays exhibit a monoexponential decay with a lifetime of 14.00 ± 0.04 ns, which is substantially shorter than the maximum values reported for bulk crystals of ~ 100 ns and is possibly related to surface defects.^{39,40}

The fabrication of the nanorod array perovskite LED adapts previous reports for planar devices, which utilized PEDOT:PSS as an ohmic hole injection layer and Ca/F8 as an electron injection layer.^{10,12} The device consists of ITO/PEDOT:PSS/ $\text{CH}_3\text{NH}_3\text{PbBr}_3$ /F8/Ca/Ag as shown in the illustration in Figure 3a. After the growth of the perovskite array on the PEDOT:PSS coated ITO, the $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array is coated with F8, which allows for electron transport while preventing quenching of emission at the interface with Ca metal.¹⁰ Afterwards, 100 nm of Ca and 300 nm of Ag is thermally evaporated to coat the nanorod array and enable electrical contact between nanorods, as show via SEM in Supporting Information Figures S1 and

S2. The metal is evaporated through a shadow mask to allow for individually addressable metal contacts between different microscale devices on the nanorod array LEDs.

For these devices, the turn-on voltage for room temperature electroluminescence is around 3.5 V of DC bias, which is 0.2 V higher than the thin film case.¹⁰ This difference may be due to the increased contact area of the nanorod array relative to the thin film.⁴¹ The electroluminescence observed from the perovskite devices is strikingly green as shown in the image as well as the spectrum of the electroluminescence (Figures 3a,b). The image of the electroluminescence was collected through the ITO/glass substrate using an inverted optical microscope. The spectrum of the electroluminescence is centered around 533 nm with a FWHM of approximately 26 nm, which indicates good color purity. This FWHM is identical to the FWHM of the photoluminescence emission, which suggests that there is good hole and electron injection into the active layer. It is notable that there is no electroluminescence that could be attributed to F8 in this device, which confirms that the role of F8 is for electron transport to the active $\text{CH}_3\text{NH}_3\text{PbBr}_3$. Both the electroluminescence image and spectrum were collected at 10 V and 8 V of bias respectively using DC pulses lasting 100 ms and spaced 200 ms apart. As seen in Figure 3d, the DC current density may exceed 10 A/cm^2 , which can lead to rapid device failure caused by Joule heating. Although this current density is high, it is notable that this value is within an order of magnitude of the current densities reported for planar thin film $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$ LEDs.¹⁰ As shown by Tan et al., the measurement range for the bias can be extended by applying a pulsed DC bias to the LEDs. Under a pulsed DC bias, light emission from the nanorod array LED continues on the time scale of several minutes when tested in ambient air. Untested LEDs remain viable in ambient air for at least 12 hours under low humidity (less than

42 percent). Improvements to the stability of the device while emitting light as well as improvements to the efficiency remain areas of active study.

To synthesize the $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorod arrays, the anion exchange to form $\text{CH}_3\text{NH}_3\text{PbI}_3$ from $\text{CH}_3\text{NH}_3\text{PbBr}_3$ has been investigated. By annealing the $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array in $\text{CH}_3\text{NH}_3\text{I}$ vapor at 150°C , anion exchange to slowly form a $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorod array is possible. The excess of $\text{CH}_3\text{NH}_3\text{I}$ provides the driving force for the anion exchange reaction. As shown in Figure 4a, the nanorod morphology can be retained after the vapor phase anion exchange reaction. The inset photo illustrates the striking conversion of the nanorod arrays from orange $\text{CH}_3\text{NH}_3\text{PbBr}_3$ to black $\text{CH}_3\text{NH}_3\text{PbI}_3$. After the anion exchange conversion, the $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorods remain single-crystalline as measured by SAED (Figure S3). The phase purity of the $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorod array was confirmed by XRD (Figure 4b). The XRD pattern can be fully indexed to the tetragonal phase of $\text{CH}_3\text{NH}_3\text{PbI}_3$. The photoluminescence properties of these films were also investigated, and no photoluminescence from $\text{CH}_3\text{NH}_3\text{PbBr}_3$ remained after the reaction was completed. At room temperature, the $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorod arrays exhibit photoluminescence at 772 nm with a FWHM of 44 nm, which is shown in Figure 4c. To our knowledge, this result is the most complete conversion of $\text{CH}_3\text{NH}_3\text{PbBr}_3$ to $\text{CH}_3\text{NH}_3\text{PbI}_3$ achieved so far. For low temperature photoluminescence, as in the case with the $\text{CH}_3\text{NH}_3\text{PbBr}_3$, a phase transition exists at 162.2 K from tetragonal to orthorhombic, which may influence the low temperature peak position (772 nm, FWHM 39 nm).

Finally, this $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorod array formed by anion exchange was applied to demonstrate room temperature electroluminescence in a device stack with an identical configuration to the $\text{CH}_3\text{NH}_3\text{PbBr}_3$ LED. These devices exhibit a much lower short circuit current density (on the order of 1 mA/cm^2) due to the increased resistivity of the LED (Figure S4). The

electroluminescence shown in Figure 4d was observed at a bias of 15 V under a pulsed DC measurement. The emission is centered at in the infrared at 782 nm with a FWHM of 41 nm, which means that all of the light emission is beyond the 720 nm limit of visible light that can be seen by the human eye. Overall, this result represents a first example of the use of anion exchange to produce new morphological control over the growth of $\text{CH}_3\text{NH}_3\text{PbI}_3$, which can be applied for functional devices.

In summary, we have demonstrated the first solution synthesis of $\text{CH}_3\text{NH}_3\text{PbBr}_3$ perovskite nanorod arrays at room temperature, and a new and straightforward anion exchange reaction to form $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorod arrays. Both of these nanorod arrays exhibit electroluminescence at room temperature. This work identifies the potential for the application of post-synthetic conversion chemistry to modify nanostructured hybrid perovskites for optoelectronic devices such as LEDs. In the future, it may be possible to apply this anion exchange technique to other systems in order to realize other types of optoelectronic devices.

FIGURES:

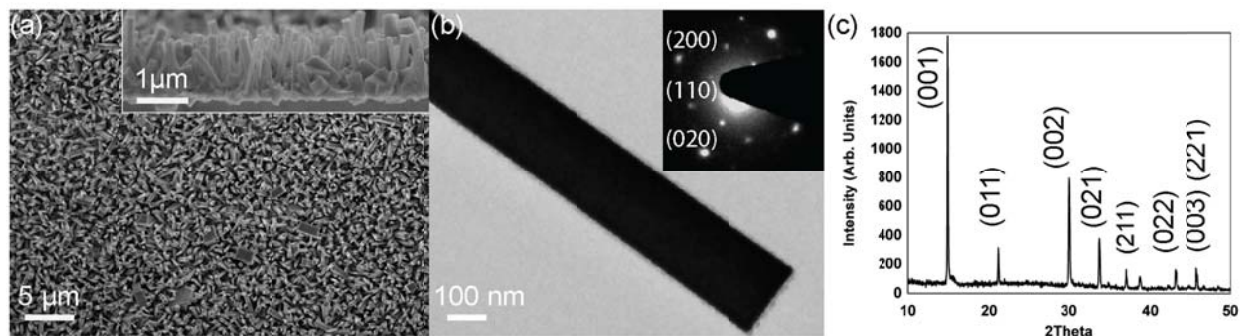


Figure 1. (a) Top view SEM image of $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array. Inset shows cross-sectional view of $\text{CH}_3\text{NH}_3\text{PbBr}_3$ array. (b) Low magnification TEM image of a $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod with inset showing the SAED of single nanorod. (c) X-ray diffraction pattern of $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array.

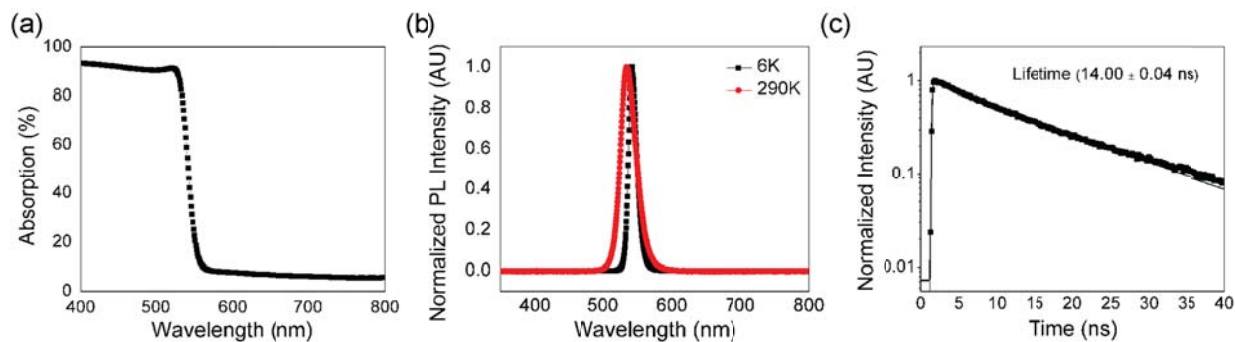


Figure 2. (a) UV-visible absorption spectrum of $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array grown on Glass/ITO/PEDOT:PSS substrate. (b) PL spectra of $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array. (c) TRPL of $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array.

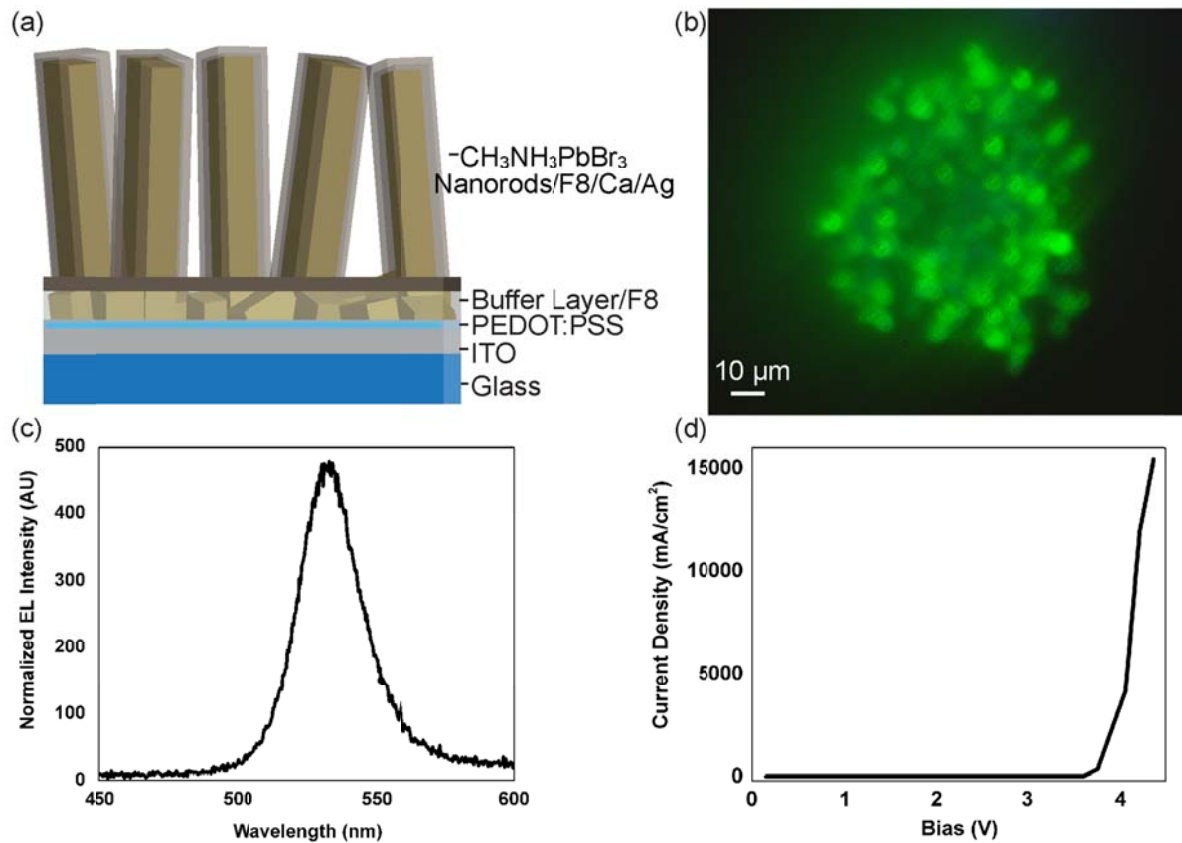


Figure 3. (a) Device structure of a $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array LED. (b) Image of the electroluminescence from the hybrid perovskite nanorod array LED. (c) Electroluminescence spectrum from the hybrid perovskite nanorod array LED. (d) IV characteristic of a hybrid perovskite LED.

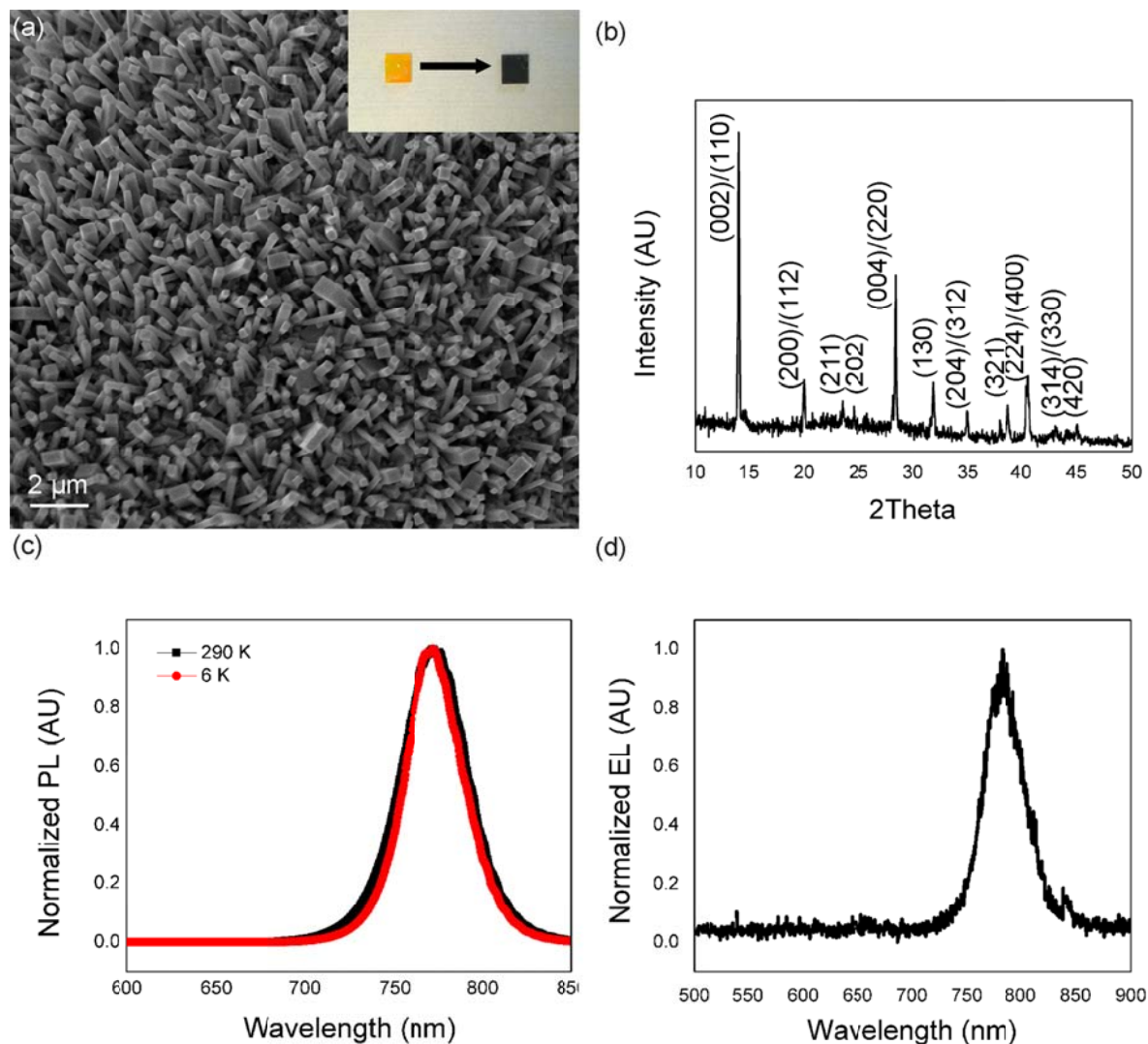


Figure 4. (a) $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorod array formed by vapor phase anion exchange of $\text{CH}_3\text{NH}_3\text{PbBr}_3$ nanorod array. Inset shows photograph of converted chip. (b) XRD pattern of $\text{CH}_3\text{NH}_3\text{PbI}_3$ from anion exchange. (c) Normalized photoluminescence of $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorod array after conversion. (d) Electroluminescence spectrum of $\text{CH}_3\text{NH}_3\text{PbI}_3$ LED.

ASSOCIATED CONTENT

Supporting Information. Experimental Methods, SEM images of LED, electron diffraction of nanorods after anion exchange, *IV* characteristic of $\text{CH}_3\text{NH}_3\text{PbI}_3$ nanorod array LED, and SEM

images illustrating growth conditions. This material is available free of charge via the Internet at <http://pubs.acs.org>.

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Author Contributions

P.Y. and A.B.W. originated the idea for the work. A.B.W., M.L., and E.L. prepared nanorod arrays. A.B.W., M.L., and Y.Y. performed the structural characterization. M.L. performed the device fabrication. A.B.W and S.W.E. characterized the optical properties of the devices and analyzed the data. The manuscript was written through contributions of all authors. All authors have given approval to the final version of the manuscript.

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Notes

The authors declare no competing financial interests.

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